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# **ST230CPbF Series**

**Vishay High Power Products** 

## **Phase Control Thyristors** (Hockey PUK Version), 410 A



- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AB (A-PUK)
- · Lead (Pb)-free
- · Designed and qualified for industrial level

#### **TYPICAL APPLICATIONS**

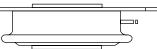
- DC motor controls
- · Controlled DC power supplies
- AC controllers

MAJOR RATINGS	AND CHARACTERISTICS		
PARAMETER	TEST CONDITIONS	VALUES	UNITS
1		410	A
I <sub>T(AV)</sub>	T <sub>hs</sub>	55	°C
1		780	A
I <sub>T(RMS)</sub>	T <sub>hs</sub>	25	°C
1	50 Hz	5700	•
60 Hz		5970	A
l <sup>2</sup> t	50 Hz	163	kA <sup>2</sup> s
1-1	60 Hz	149	KA-5
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 2000	V
t <sub>q</sub>	Typical	100	μs
TJ		- 40 to 125	°C

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE R	ATINGS			
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I <sub>DRM</sub> /I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = T <sub>J</sub> MAXIMUM mA
	04	400	500	
	08	800	900	
	12	1200	1300	
ST230CC	14	1400	1500	30
	16	1600	1700	
	18	1800	1900	]
	20	2000	2100	

For technical questions, contact: ind-modules@vishay.com



410 A



TO-200AB (A-PUK)

**PRODUCT SUMMARY** 

I<sub>T(AV)</sub>



RoHS COMPLIANT

## **ST230CPbF Series**

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ABSOLUTE MAXIMUM RATIN	GS						
PARAMETER	SYMBOL		TEST CON	IDITIONS	VALUES	UNITS	
Maximum average on-state current		180° condu	ction, half sine v	410 (165)	А		
at heatsink temperature	I <sub>T(AV)</sub>	double side	double side (single side) cooled		55 (85)	°C	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 25 °C	heatsink tempe	erature double side cooled	780		
		t = 10 ms	No voltage		5700		
Maximum peak, one-cycle non-repetitive surge current		t = 8.3 ms	reapplied		5970	А	
	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		4800		
		t = 8.3 ms	reapplied	Sinusoidal half wave,	5000		
	l <sup>2</sup> t	t = 10 ms	s reapplied	initial $T_J = T_J$ maximum	163	- kA <sup>2</sup> s	
<b>M</b> · · · · · · · · · · · · · · · · · · ·		t = 8.3 ms			148		
Maximum I <sup>2</sup> t for fusing	141	t = 10 ms			115		
		t = 8.3 ms	reapplied		105		
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 to 10	ms, no voltage	reapplied	1630	kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$ ), $T_J = T_J$ maximum	0.92		
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)})$	<sub>()</sub> ), T <sub>J</sub> = T <sub>J</sub> maxii	num	0.98	V	
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$ ), $T_J = T_J$ maximum	0.88		
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi x I_{T(AV)}), T_J = T_J maximum$		0.81	mΩ		
Maximum on-state voltage	V <sub>TM</sub>	$I_{pk} = 880 \text{ A}, T_J = T_J \text{ maximum, } t_p = 10 \text{ ms sine pulse}$			1.69	V	
Maximum holding current	Ι <sub>Η</sub>	$T_{J} = 25 \text{ °C}$ , anode supply 12 V resistive load		600			
Maximum (typical) latching current	١L	$I_{\rm J} = 25 {}^{\rm s}{\rm C},$	anode supply 12	2 v resistive load	1000 (300)	mA	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega,  t_r \leq$ 1 $\mu s$ $T_J$ = $T_J$ maximum, anode voltage $\leq$ 80 % $V_{DRM}$	1000	A/µs
Typical delay time	t <sub>d</sub>	Gate current 1 A, dl <sub>g</sub> /dt = 1 A/ $\mu$ s V <sub>d</sub> = 0.67 % V <sub>DRM</sub> , T <sub>J</sub> = 25 °C	1.0	
Typical turn-off time	tq	$ \begin{array}{l} \textbf{I}_{TM} = 300 \text{ A}, \ \textbf{T}_{J} = \textbf{T}_{J} \text{ maximum, } \textbf{dI/dt} = 20 \text{ A/}\mu \textbf{s}, \\ \textbf{V}_{R} = 50 \text{ V}, \ \textbf{dV/dt} = 20 \text{ V/}\mu \textbf{s}, \ \textbf{gate } 0 \text{ V} 100 \ \Omega, \ \textbf{t}_{p} = 500 \ \mu \textbf{s} \end{array} $	100	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$	500	V/µs
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	30	mA



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TRIGGERING								
PARAMETER	OVMBOL	те	VAL					
PARAMETER	STMBOL	SYMBOL TEST CONDITIONS				UNITS		
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum	, $t_p \le 5 \text{ ms}$	10	).0	w		
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum	, f = 50 Hz, d% = 50	2	.0	vv		
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum	, $t_p \le 5 \text{ ms}$	3	.0	А		
Maximum peak positive gate voltage	+ V <sub>GM</sub>		+ < E mo	2	0	v		
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J maximum$	5.0					
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C		180	-			
DC gate current required to trigger		T <sub>J</sub> = 25 °C	Maximum required gate trigger/	90	150	mA		
		T <sub>J</sub> = 125 °C	current/voltage are the lowest	40	-			
		T <sub>J</sub> = - 40 °C	value which will trigger all units	2.9	-			
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C	12 V anode to cathode applied	1.8	3.0	V		
		T <sub>J</sub> = 125 °C		1.2	-			
DC gate current not to trigger	I <sub>GD</sub>	Maximum gate current/voltage not to trigger is the maximum		10		mA		
DC gate voltage not to trigger	V <sub>GD</sub>	$T_J = T_J maximum$	value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	0.25		V		

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS			
Maximum operating temperature rangeT_JMaximum storage temperature rangeT_Stg			- 40 to 125	°C			
			- 40 to 150	U			
Maximum thermal resistance,	R <sub>thJ-hs</sub>	DC operation single side cooled	0.17				
junction to heatsink	nthJ-hs	DC operation double side cooled	0.08	K/W			
Maximum thermal resistance,	R <sub>thC-bs</sub>	DC operation single side cooled	0.033				
case to heatsink	nthC-hs	DC operation double side cooled	0.017				
Mounting force, $\pm 10$ %			4900	Ν			
			(500)	(kg)			
Approximate weight			50	g			
Case style		See dimensions - link at the end of datasheet	TO-200AB (A	A-PUK)			

CONDUCTION ANGLE	SINUSOIDAL CONDUCT		RECTANGULA	R CONDUCTION	TEST CONDITIONS				
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE DOUBLE SIDE		TEST CONDITIONS	NS UNITS			
180°	0.015	0.017	0.011	0.011					
120°	0.018	0.019	0.019	0.019					
90°	0.024	0.024	0.026	0.026	$T_J = T_J$ maximum	K/W			
60°	0.035	0.035	0.036	0.036					
30°	0.060	0.060	0.060	0.061					

Note

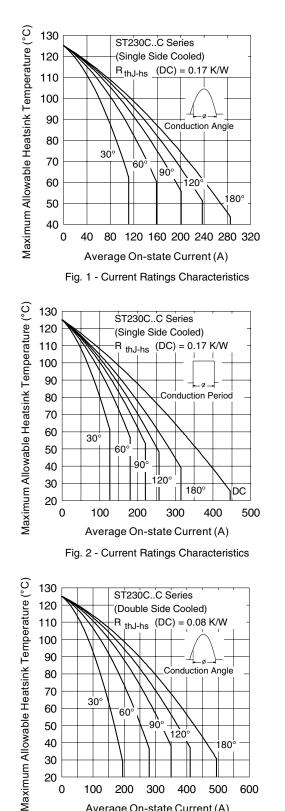
- The table above shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC

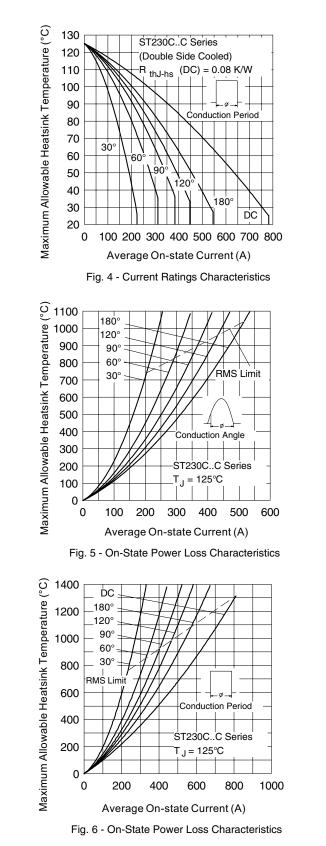
## ST230CPbF Series

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30

20

0

100

200

300

Average On-state Current (A)

Fig. 3 - Current Ratings Characteristics

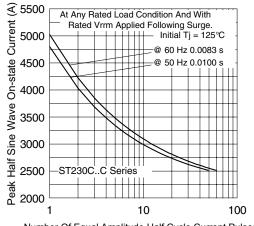
400

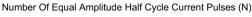
500

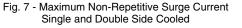
600

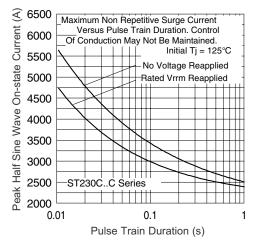


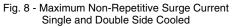
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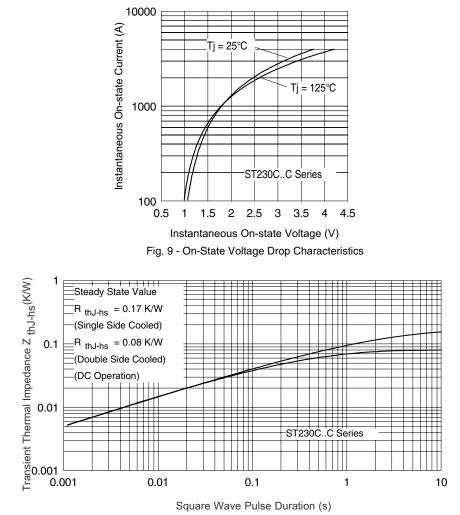


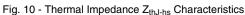




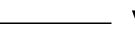






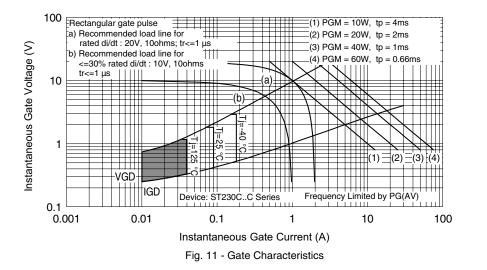


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### **ORDERING INFORMATION TABLE**

Device code	ST	23	0	с	20	С	1		PbF	
·	1	2	3	4	5	6	7	8	9	
]	1 -	Thy	ristor							
[	2 -	Ess	ential p	art numl	ber					
]	3 -	0 =	Conver	ter grad	е					
[	4 -	C =	Cerami	c PUK						
	5 -	Volt	age coo	le x 100	= V <sub>RRN</sub>	<sub>1</sub> (see V	oltage F	Ratings	table)	
[	6 -	C =	PUK ca	ise TO-2	200AB (	A-PUK)				
[	7 -	0 =	Eyelet t	erminals	s (gate a	and aux	iliary ca	thode u	insoldered	leads)
		1 =	Fast-on	termina	als (gate	and au	xiliary c	athode	unsoldere	d leads)
		2 =	Eyelet t	erminal	s (gate a	and aux	iliary ca	thode s	oldered lea	ads)
		3 =	Fast-on	termina	als (gate	and au	xiliary c	athode	soldered le	eads)
[	8 -	Criti	ical dV/	dt: • No	ne = 50	0 V/µs (	Standaı	rd selec	tion)	
_				• L =	1000 V	/µs (Sp	ecial se	lection)		
[	9 -	Lea	d (Pb)-f	ree						

LINKS TO RELATED DOCUMENTS					
Dimensions	http://www.vishay.com/doc?95074				

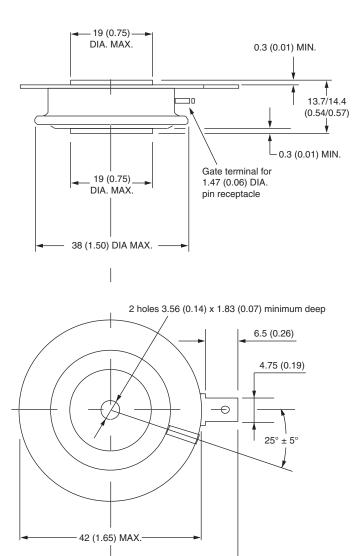


**Vishay Semiconductors** 

## TO-200AB (A-PUK)

#### **DIMENSIONS** in millimeters (inches)

Anode to gate Creepage distance: 7.62 (0.30) minimum Strike distance: 7.12 (0.28) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)

28 (1.10)



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